

L Number	Hits	Search Text	DB	Time stamp
1	140	(power adj plant) and (gear adj reduction)	USPAT; US-PGPUB	2003/04/11 14:39
2	51	((power adj plant) and (gear adj reduction)) and turbine	USPAT; US-PGPUB	2003/04/11 14:39
4	2	(((power adj plant) and (gear adj reduction)) and turbine) and mount\$4) and transportation	USPAT; US-PGPUB	2003/04/11 14:40
3	44	(((power adj plant) and (gear adj reduction)) and turbine) and mount\$4	USPAT; US-PGPUB	2003/04/11 14:40
-	258	(60/796).CCLS.	USPAT; US-PGPUB	2003/04/11 10:22
-	20692	power adj plant	USPAT; US-PGPUB	2003/04/11 14:38
-	18	((60/796).CCLS.) and (power adj plant)	USPAT; US-PGPUB	2003/04/11 10:27
-	4	("2124395" "3005518" "3290793" "3623573").PN.	USPAT	2003/04/11 10:26
-	3	((60/796).CCLS.) and transportation	USPAT; US-PGPUB	2003/04/11 10:31
-	2	("3418485" "4002023").PN.	USPAT	2003/04/11 10:29
1834		(power adj plant) and transportation	USPAT; US-PGPUB	2003/04/11 13:03
-	135	(power adj plant) and (transportation near vehicle)	USPAT; US-PGPUB	2003/04/11 12:56
-	6	("2432228" "2541288" "3228352" "3285194" "3369684" "3584584").PN.	USPAT	2003/04/11 10:56
-	15	truck same (gas adj turbine) same mount\$4	USPAT; US-PGPUB	2003/04/11 12:51
-	2	jp-2001173408-\$ did.	EPO; JPO; DERWENT; IBM_TDB	2003/04/11 11:23
-	2	jp-11062621-\$ did.	EPO; JPO; DERWENT; IBM_TDB	2003/04/11 11:39
-	2	jp-11013416-\$ did.	EPO; JPO; DERWENT; IBM_TDB	2003/04/11 11:26
-	1	jp-59224407-\$ did.	EPO; JPO; DERWENT; IBM_TDB	2003/04/11 11:39
-	7	("RE30280" "RE30229" "3925679" "3720446" "3770232" "4385774" "4245158").PN.	USPAT	2003/04/11 12:53
-	3	("3461633" "3489911" "3848138").PN.	USPAT	2003/04/11 12:54
-	38	turbine same (transportation near vehicle)	USPAT; US-PGPUB	2003/04/11 14:01
-	973	((power adj plant) and transportation) and mount\$4	USPAT; US-PGPUB	2003/04/11 13:04
-	115	(((power adj plant) and transportation) and mount\$4) and modular	USPAT; US-PGPUB	2003/04/11 13:04
-	2	("1522612" "2086036").PN.	USPAT	2003/04/11 13:21
-	16	(power adj plant) same (transportation near vehicle)	EPO; JPO; DERWENT; IBM_TDB	2003/04/11 14:02
-	3	turbine same (transportation near vehicle)	EPO; JPO; DERWENT; IBM_TDB	2003/04/11 14:04
-	11	turbine same (transportation near vehicle)	USOCR	2003/04/11 14:16
119313		(29/\$).CCLS.	USPAT; US-PGPUB	2003/04/11 14:17
-	0	("25 and power adj plant").PN.	USPAT; US-PGPUB	2003/04/11 14:17
-	374	((29/\$).CCLS.) and power adj plant	USPAT; US-PGPUB	2003/04/11 14:21
-	28	(((29/\$).CCLS.) and power adj plant) and truck	USPAT; US-PGPUB	2003/04/11 14:21

-	58626	(60/\$).CCLS.	USPAT; US-PGPUB	2003/04/11 14:21
-	3422	((60/\$).CCLS.) and power adj plant	USPAT; US-PGPUB	2003/04/11 14:21
-	180	(((60/\$).CCLS.) and power adj plant) and truck	USPAT; US-PGPUB	2003/04/11 14:21
-	139	(((60/\$).CCLS.) and power adj plant) and truck) and turbine	USPAT; US-PGPUB	2003/04/11 14:21
-	74	((((60/\$).CCLS.) and power adj plant) and truck) and turbine) and mount\$4	USPAT; US-PGPUB	2003/04/11 14:22

10081202_CLS

Most Frequently Occurring Classifications of Patents Returned
From A Search of 10081202 on April 11, 2003

Original Classifications

2 330/149
2 330/264
2 330/277
2 330/288
2 330/300
2 330/51

Cross-Reference Classifications

8 330/311
3 257/E29.032
3 330/255
2 257/E29.026
2 323/314
2 327/434
2 330/257
2 330/258
2 330/260
2 330/263
2 330/265
2 330/294
2 330/296
2 330/306

Combined Classifications

9 330/311
4 330/255
3 257/E29.032
3 330/263
3 330/264
3 330/265
3 330/277
3 330/300
2 257/E29.026
2 323/314
2 323/316
2 327/377
2 327/432
2 327/434
2 330/149
2 330/256
2 330/257
2 330/258
2 330/260

10081202_CLS

2 330/274
2 330/286
2 330/288
2 330/294
2 330/296
2 330/306
2 330/51
2 331/116R
2 363/132

10081202_CLSTITLES

Titles of Most Frequently Occurring Classifications of Patents Returned

From A Search of 10081202 on April 11, 2003

9 330/311 (1 OR, 8 XR)
Class 330 : AMPLIFIERS
330/250 WITH SEMICONDUCTOR AMPLIFYING DEVICE (E.G.,
TRANSISTOR)
330/310 . Including plural stages cascaded
330/311 .. Having different configurations

4 330/255 (1 OR, 3 XR)
Class 330 : AMPLIFIERS
330/250 WITH SEMICONDUCTOR AMPLIFYING DEVICE (E.G.,
TRANSISTOR)
330/252 . Including differential amplifier
330/255 .. Having push-pull amplifier stage

3 257/E29.032 (0 OR, 3 XR)
Class 257 : ACTIVE SOLID-STATE DEVICES
257/E29.001 DETAILS OF SEMICONDUCTOR BODIES OR ELECTRODES
OF SEMICONDUCTOR DEVICES ADAPTED FOR R
ECTIFYING,
AMPLIFYING, OSCILLATING OR SWITCHING,
OR CAPACITORS OR
RESISTORS WITH AT LEAST ONE POTENTIAL
BARRIER OR SURFACE
AYER OR CARRIER
CONCENTRATION LAYER) (EPO)
257/E29.002 . Electrical characteristics due to properties
of entire semiconductor body rather tha
n just surface
region (EPO)
257/E29.005 .. Characterized by specified shape or size of
centration gradient
PN junction or by specified impurity con
within device (EPO)
257/E29.029 ... With semiconductor regions connected to
d, amplified, or
semiconductor
trodes (EPO)
switched and such electrode being part of
device which comprises three or more elec
257/E29.03 . . . Emitter regions of bipolar transistors
(EPO)

10081202_CLSTITLES

257/E29.032 Noninterconnected multiemitter structures
(EPO)

3 330/263 (1 OR, 2 XR)

Class 330 : AMPLIFIERS

330/250 WITH SEMICONDUCTOR AMPLIFYING DEVICE (E.G.,
TRANSISTOR)

330/262 . Including push-pull amplifier

330/263 .. Having complementary symmetry

3 330/264 (2 OR, 1 XR)

Class 330 : AMPLIFIERS

330/250 WITH SEMICONDUCTOR AMPLIFYING DEVICE (E.G.,
TRANSISTOR)

330/262 . Including push-pull amplifier

330/263 .. Having complementary symmetry

330/264 ... And field effect transistor

3 330/265 (1 OR, 2 XR)

Class 330 : AMPLIFIERS

330/250 WITH SEMICONDUCTOR AMPLIFYING DEVICE (E.G.,
TRANSISTOR)

330/262 . Including push-pull amplifier

330/263 .. Having complementary symmetry

330/265 ... And feedback means

3 330/277 (2 OR, 1 XR)

Class 330 : AMPLIFIERS

330/250 WITH SEMICONDUCTOR AMPLIFYING DEVICE (E.G.,
TRANSISTOR)

330/277 . Including field effect transistor

3 330/300 (2 OR, 1 XR)

Class 330 : AMPLIFIERS

330/250 WITH SEMICONDUCTOR AMPLIFYING DEVICE (E.G.,
TRANSISTOR)

330/299 . Including combined diverse-type semiconductor
device

330/300 .. Bipolar or unipolar (FET)

2 257/E29.026 (0 OR, 2 XR)

Class 257 : ACTIVE SOLID-STATE DEVICES

257/E29.001 DETAILS OF SEMICONDUCTOR BODIES OR ELECTRODES
OF SEMICONDUCTOR DEVICES ADAPTED FOR RE

CTIFYING,

AMPLIFYING, OSCILLATING OR SWITCHING, O

R CAPACITORS OR

RESISTORS WITH AT LEAST ONE POTENTIAL B

10081202_CLSTITLES

2 327/432 (1 OR, 1 XR)
Class 327 : MISCELLANEOUS ACTIVE ELECTRICAL NONLINEAR
DEVICES, CIRCUITS, AND SYSTEMS
327/365 GATING (I.E., SWITCHING INPUT TO OUTPUT)
327/419 .Utilizing three or more electrode solid-state
device
327/427 ..Field-effect transistor
327/432 ...With bipolar transistor

2 327/434 (0 OR, 2 XR)
Class 327 : MISCELLANEOUS ACTIVE ELECTRICAL NONLINEAR
DEVICES, CIRCUITS, AND SYSTEMS
327/365 GATING (I.E., SWITCHING INPUT TO OUTPUT)
327/419 .Utilizing three or more electrode solid-state
device
327/427 ..Field-effect transistor
327/434 ...Insulated gate FET (e.g., MOSFET, etc.)

2 330/149 (2 OR, 0 XR)
Class 330 : AMPLIFIERS
330/149 HUM OR NOISE OR DISTORTION BUCKING INTRODUCED
INTO SIGNAL CHANNEL

2 330/256 (1 OR, 1 XR)
Class 330 : AMPLIFIERS
330/250 WITH SEMICONDUCTOR AMPLIFYING DEVICE (E.G.,
TRANSISTOR)
330/252 ..Including differential amplifier
330/256 ..Having temperature compensation means

2 330/257 (0 OR, 2 XR)
Class 330 : AMPLIFIERS
330/250 WITH SEMICONDUCTOR AMPLIFYING DEVICE (E.G.,
TRANSISTOR)
330/252 ..Including differential amplifier
330/257 ..Having current mirror amplifier

2 330/258 (0 OR, 2 XR)
Class 330 : AMPLIFIERS
330/250 WITH SEMICONDUCTOR AMPLIFYING DEVICE (E.G.,
TRANSISTOR)
330/252 ..Including differential amplifier
330/258 ..Having common mode rejection circuit

2 330/260 (0 OR, 2 XR)
Class 330 : AMPLIFIERS
330/250 WITH SEMICONDUCTOR AMPLIFYING DEVICE (E.G.,
TRANSISTOR)

10081202_CLSTITLES

330/252 . Including differential amplifier
330/260 .. Having signal feedback means

2 330/274 (1 OR, 1 XR)
Class 330 : AMPLIFIERS
330/250 WITH SEMICONDUCTOR AMPLIFYING DEVICE (E.G.,
TRANSISTOR)
330/262 . Including push-pull amplifier
330/273 .. Having particular biasing arrangement
330/274 ... To eliminate crossover distortion

2 330/286 (1 OR, 1 XR)
Class 330 : AMPLIFIERS
330/250 WITH SEMICONDUCTOR AMPLIFYING DEVICE (E.G.,
TRANSISTOR)
330/286 . Including distributed parameter-type coupling

2 330/288 (2 OR, 0 XR)
Class 330 : AMPLIFIERS
330/250 WITH SEMICONDUCTOR AMPLIFYING DEVICE (E.G.,
TRANSISTOR)
330/288 . Including current mirror amplifier

2 330/294 (0 OR, 2 XR)
Class 330 : AMPLIFIERS
330/250 WITH SEMICONDUCTOR AMPLIFYING DEVICE (E.G.,
TRANSISTOR)
330/291 . Including signal feedback means
330/294 .. Having frequency-responsive means or
phase-shift means in feedback path

2 330/296 (0 OR, 2 XR)
Class 330 : AMPLIFIERS
330/250 WITH SEMICONDUCTOR AMPLIFYING DEVICE (E.G.,
TRANSISTOR)
330/296 . Including particular biasing arrangement

2 330/306 (0 OR, 2 XR)
Class 330 : AMPLIFIERS
330/250 WITH SEMICONDUCTOR AMPLIFYING DEVICE (E.G.,
TRANSISTOR)
330/302 . Including frequency-responsive means in the
signal transmission path
330/306 .. And bandpass, broadband (e.g., wideband) or
sidepass means

2 330/51 (2 OR, 0 XR)

10081202 CLSTITLES

Class 330 : AMPLIFIERS
330/51 COMBINED WITH AUTOMATIC AMPLIFIER DISABLING
SWITCH MEANS

2 331/116R (1 OR, 1 XR)

Class 331 : OSCILLATORS

331/107R SOLID STATE ACTIVE ELEMENT OSCILLATOR

331/108R .Transistors

331/116R ..Electromechanical resonator controlled

2 363/132 (1 OR, 1 XR)

Class 363 : ELECTRIC POWER CONVERSION SYSTEMS

363/25With automatic control of the magnitude of

f output voltage or current

363/123 .Using semiconductor-type converter

363/131 ..In transistor inverter systems

363/132 ...Bridge type